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Application Number

10/784,606

Filing Date

February 23, 2004

First Named Inventor

Frank DiMeo, Jr.

Group Art Unit

2856

Examiner Name

TBA

Total Number of Pages in This Submission

Attorney Docket Number

ATMI-546-CIP-I

ENCLOSURES (check all that apply)

- Fee Transmittal Form
- Fee Attached
- Amendment / Reply
- After Final
- Affidavits/declaration(s)
- Extension of Time Request
- Express Abandonment Request
- Information Disclosure Statement
- Certified Copy of Priority Document(s)
- Response to Missing Parts/ Incomplete Application
 - Response to Missing Parts under 37 CFR 1.52 or 1.53

- Assignment Papers (for an Application)
- Drawing(s)
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- Petition
- Petition to Convert to a Provisional Application
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- Terminal Disclaimer
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Remarks

SIGNATURE OF APPLICANT, ATTORNEY, OR AGENT

Firm or Individual name

Margaret Chappuis, Reg. No. 45,735

Signature

Date

August 31, 2004

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ATMI-546-CIP-I
Customer ID No.: 25559

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Frank DiMeo, Jr.

Group Art Unit: 2856

U.S. Application No.: 10/784,606

Examiner: TBA

Filed: February 23, 2004

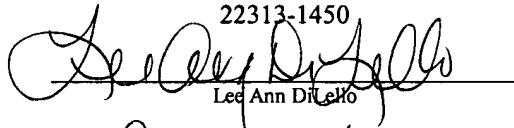
Title: NICKEL-COATED FREE-STANDING SILICON CARBIDE STRUCTURE FOR
SENSING FLUORO OR HALOGEN SPECIES IN SEMICONDUCTOR PROCESSING
SYSTEMS, AND PROCESSES OF MAKING AND USING SAME

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INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
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Sir:

Pursuant to 37 C.F.R. §1.56, the attention of the Patent and Trademark Office is hereby directed to the reference(s) listed on the attached PTO-1449. It is respectfully requested that the information be expressly considered during the prosecution of this application, and that the reference(s) be made of record therein and appear among the "References Cited" on any patent to issue therefrom.

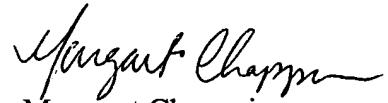
1. This Information Disclosure Statement is being filed within three months of the U.S. filing date OR before the mailing date of a first Office Action on the merits. No certification or fee is required in accordance with 37 CFR § 1.56 and § 1.97(b). Please note that Reference AH "Inorganic Solid Fluorides, Chemistry and Physics" is a book and

is not enclosed. Should a copy of this reference be required, Applicants will provide a copy.

- 2. This Information Disclosure Statement is being filed more than three months after the U.S. filing date AND after the mailing date of the first Office Action on the merits, but before the mailing date of a Final Rejection or Notice of Allowance.
 - a. I hereby certify that each item of information contained in this Information Disclosure Statement was the first citation of such item by a foreign patent office in a counterpart foreign application, which occurred no more than three months prior to filing the Information Disclosure Statement. 37 C.F.R. §1.97(e)(1).
 - b. I hereby certify that no item of information in this Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application or, to my knowledge after making reasonable inquiry, was known to any individual designated in 37 CFR §1.56(c) more than three months prior to the filing of this Information Disclosure Statement. 37 C.F.R. §1.97(e)(2).
 - c. Attached is our check no. ____ in the amount of \$180 in payment of the fee under 37 C.F.R. §1.17(p). Please credit or debit Deposit Account No. 50-0860 as needed to ensure consideration of the disclosed information. Two duplicate copies of this paper are attached.
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- 4. (other):

Applicant does not believe that any additional fee is due in connection with the foregoing. However, any deficiencies may be charged to the deposit account 50-0860.

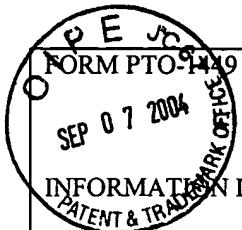
Respectfully submitted,



Margaret Chappuis
Registration No. 45,735
Agent for Applicant

Date: *August 31, 2004*

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Danbury, CT 06810
Agent Ref: ATMI-546-CIP-I

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|  | | US Dept. of Commerce Patent and Trademark Office | | ATTORNEY DOCKET NO. | SERIAL NO. | | |
| | | | | ATMI-546-CIP-I | 10/784,606 | | |
| | | | | APPLICANT | | | |
| | | | | Frank DiMeo, Jr. | | | |
| | | | | FILING DATE | GROUP | | |
| | | | | February 23, 2004 | 2856 | | |

U.S. PATENT DOCUMENTS

| EXAMINER INITIAL | | PATENT NUMBER | ISSUE DATE | NAME | CLASS | SUBCLASS | FILING DATE IF APPROPRIATE |
|------------------|----|---------------|------------|--------------------------|-------|----------|----------------------------|
| | AA | 10/273,036 | 10/17/2002 | Frank DiMeo, Jr., et al. | | | |
| | AB | 6,265,222 | 6/24/2001 | Frank DiMeo, Jr., et al. | | | |
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FOREIGN PATENT DOCUMENTS

| | | DOCUMENT NUMBER | PUBLICATION DATE | COUNTRY | CLASS | SUBCLAS S | TRANSLATION YES | NO |
|--|--|-----------------|------------------|---------|-------|-----------|----------------------|----|
| | | | | | | | X (abstract only) | |

OTHER DOCUMENTS (Including Author, Title, Journal-Date, Page Number, Etc.)

| | | |
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| | AG | Anderson, B, et al., Semiconductor International, October (1993) |
| | AH | Inorganic Solid Fluorides, Chemistry and Physics, Academic Press, 1985, Ed P. Hagenmuller. (See Information Disclosure Statement Box 1) |
| | AI | W. Moritz, et al., Sensors and Actuators B 24-25 (1995) 194-196, "Monitoring of HF and F2 using a field-effect sensor" |
| | AJ | Dr. Shigeru Kurosawa, et al., Fluorine in Coatings II, Paper 33, pgs. 1-8, "Plasma Polymerisation of Fluorine Contained Polycyclic Compounds: Its Application in Chemical Sensors" |
| | AK | Werner Moritz, et al., The 11th European Conference on Solid State Transducers, Warsaw, Poland, pgs. 111-114, September 21-24, 1997, "Gas Sensors for Fluorine Using Different Semiconductor Substrates" |
| | AL | W. Moritz, et al., 1998 American Chemical Society, Chapter 10, pgs. 119-129, "Silicon-Based Sensor for Fluorine Gas" |
| | AM | Semiconductor International, "Residual Gas Analysis", Oct. 1997, pgs. 94-100 |

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|----------|-----------------|
| EXAMINER | DATE CONSIDERED |
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